

PJA3438-AU

50V N-Channel Enhancement Mode MOSFET – ESD Protected

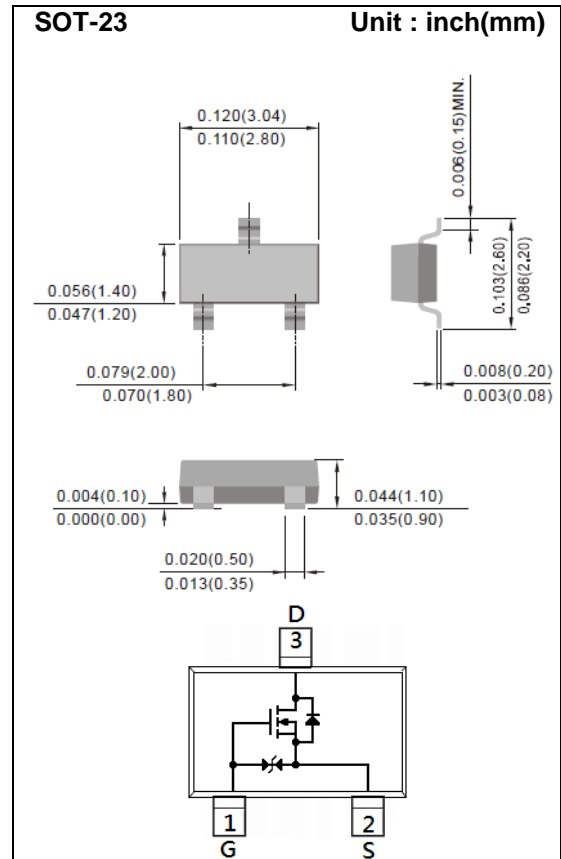
Voltage 50 V **Current** 500mA

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@500mA < 1.45\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@200mA < 1.95\Omega$
- $R_{DS(ON)}$, $V_{GS}@2.5V$, $I_D@100mA < 4.0\Omega$
- $R_{DS(ON)}$, $V_{GS}@1.8V$, $I_D@10mA < 6.0\Omega$
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	50	V
Gate-Source Voltage	V_{GS}	+20	
Continuous Drain Current	I_D	500	mA
Pulsed Drain Current	I_{DM}	1200	
Power Dissipation	$T_A=25^\circ\text{C}$	500	mW
	Derate above 25°C	4	mW/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance	$R_{\theta JA}$	250	$^\circ\text{C/W}$
- Junction to Ambient (Note 3)			

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	50	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.5	0.86	1.0	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =500mA	-	1.2	1.45	Ω
		V _{GS} =4.5V, I _D =200mA	-	1.3	1.95	
		V _{GS} =2.5V, I _D =100mA	-	1.7	4.0	
		V _{GS} =1.8V, I _D =10mA	-	4.0	6.0	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =50V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±10	
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =25V, I _D =500mA, V _{GS} =4.5V	-	0.95	-	nC
Gate-Source Charge	Q _{gs}		-	0.34	-	
Gate-Drain Charge	Q _{gd}		-	0.32	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	36	-	pF
Output Capacitance	C _{oss}		-	11	-	
Reverse Transfer Capacitance	C _{rss}		-	6.6	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =25V, I _D =500mA, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	2.3	-	ns
Turn-On Rise Time	t _r		-	20	-	
Turn-Off Delay Time	t _{d(off)}		-	7	-	
Turn-Off Fall Time	t _f		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _s	---	-	-	500	mA
Diode Forward Voltage	V _{SD}	I _s =500mA, V _{GS} =0V	-	0.9	1.5	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

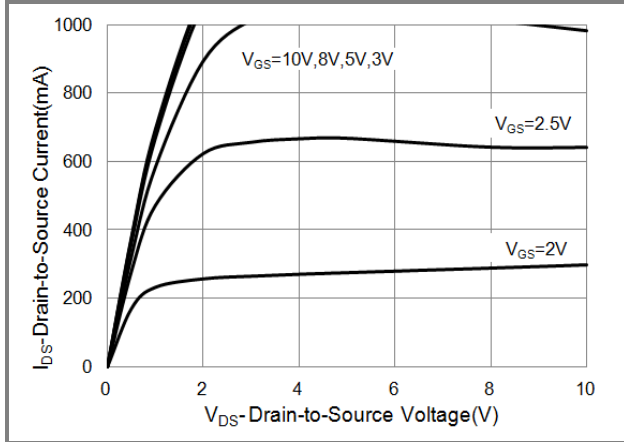


Fig.1 On-Region Characteristics

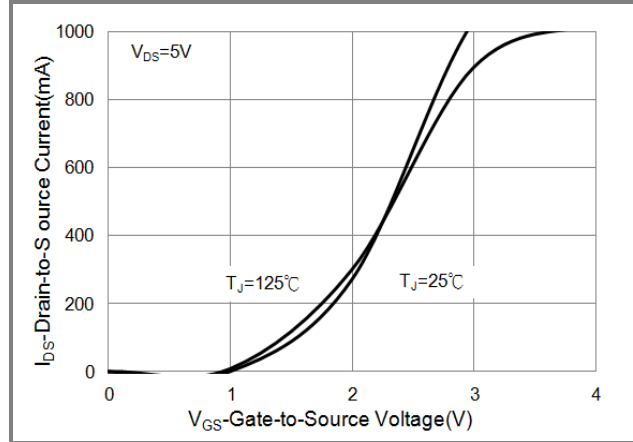


Fig.2 Transfer Characteristics

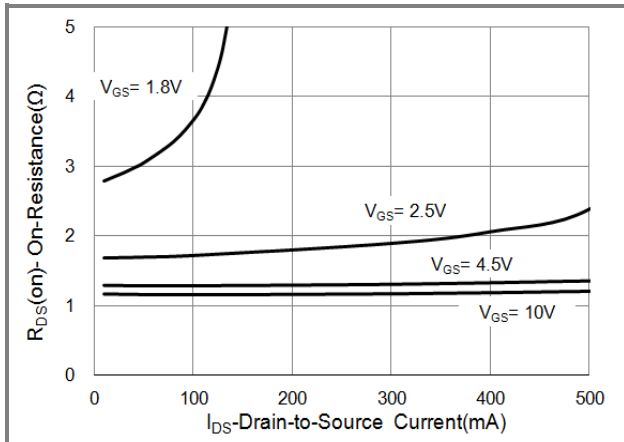


Fig.3 On-Resistance vs. Drain Current

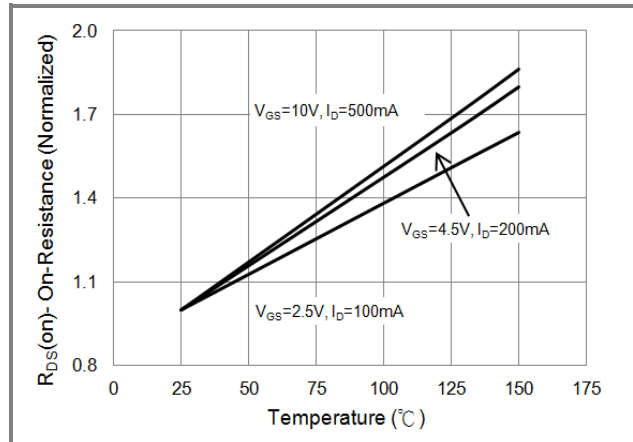


Fig.4 On-Resistance vs. Junction temperature

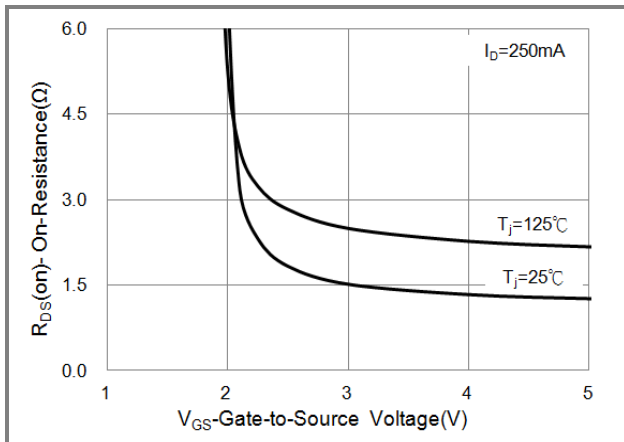


Fig.5 On-Resistance Variation with V_{GS}

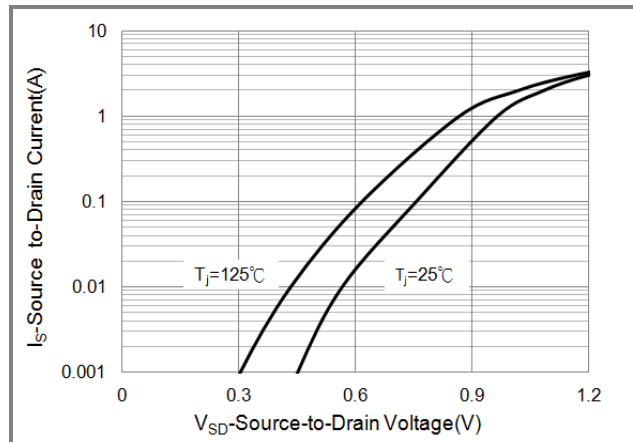


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

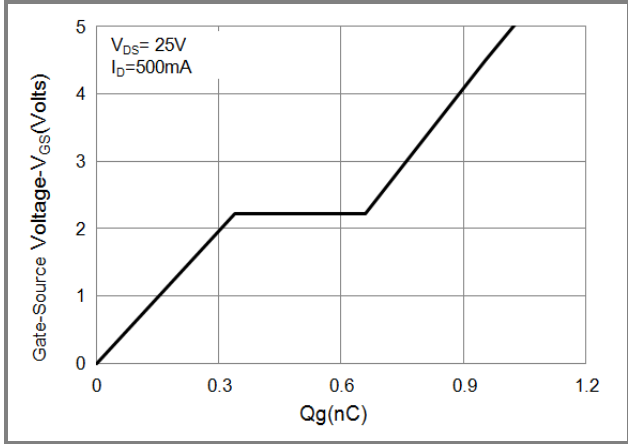


Fig.7 Gate-Charge Characteristics

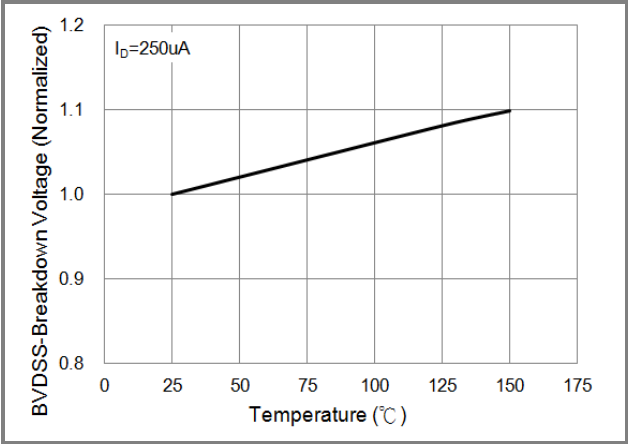


Fig.8 Breakdown Voltage Variation vs. Temperature

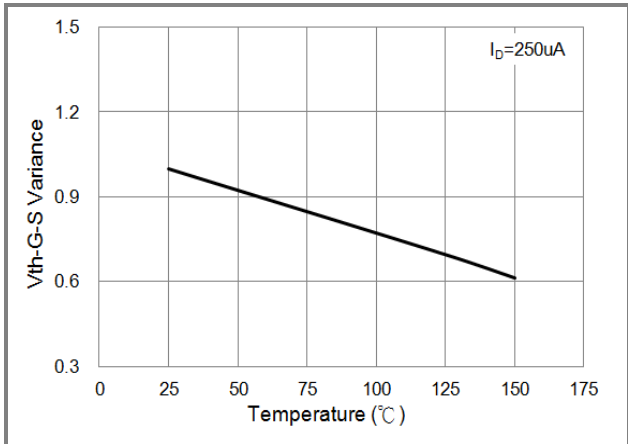


Fig.9 Threshold Voltage Variation with Temperature

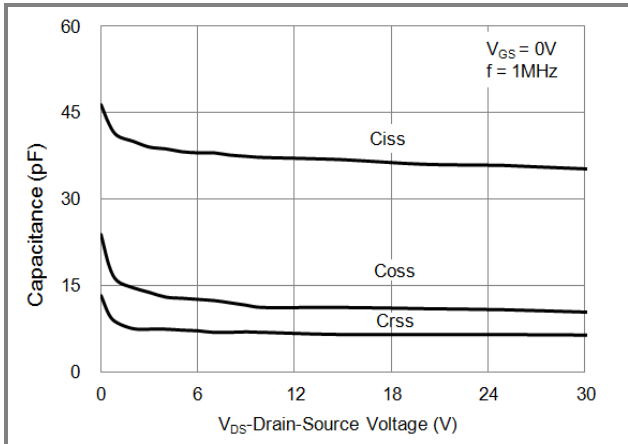


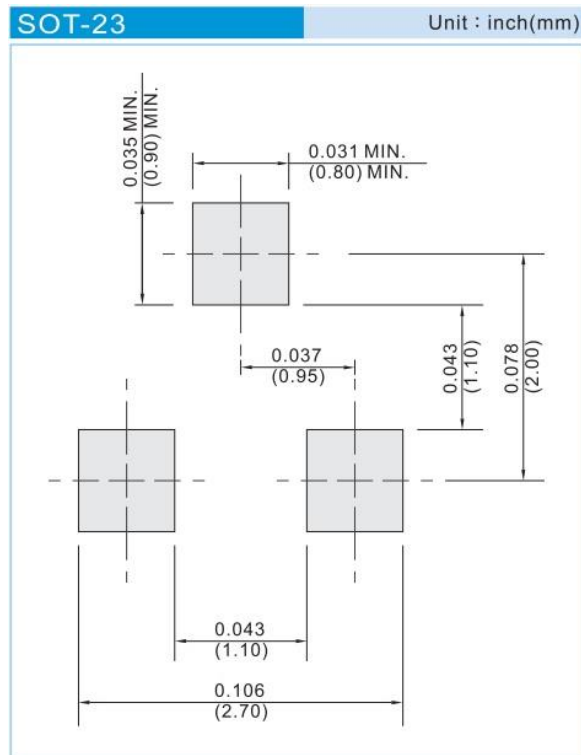
Fig.10 Capacitance vs. Drain-Source Voltage

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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJA3438-AU	SOT-23	3K pcs / 7" reel	A38

Mounting Pad Layout



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